

## High Efficiency LEDs in $\varnothing$ 5 mm Tinted Diffused Package

Color	Type	Technology	Angle of half intensity $\pm\varphi$
High efficiency red	TLHR54../TLHR64..	GaAsP on GaP	30°
Yellow	TLHY54../TLHY64..	GaAsP on GaP	
Green	TLHG54../TLHG64..	GaP on GaP	

### Description

The TLH.54.. and 64.. series was developed for standard applications like general indicating and lighting purposes.

It is housed in a 5 mm tinted diffused plastic package. The wide viewing angle of these devices provides a high on-off contrast.

Several selection types with different luminous intensities are offered. All LEDs are categorized in luminous intensity groups. The green and yellow LEDs are categorized additionally in wavelength groups.

That allows users to assemble LEDs with uniform appearance.

### Features

- Choice of three bright colors
- Standard T-1 $\frac{3}{4}$  package
- Small mechanical tolerance
- Suitable for DC and high peak current
- Wide viewing angle
- Luminous intensity categorized
- Yellow and green color categorized
- TLH.54.. with stand offs
- TLH.64.. without stand offs

### Applications

Status lights  
OFF / ON indicator  
Background illumination  
Readout lights  
Maintenance lights  
Legend light

## TLH.54../64..

### Absolute Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

TLHR54../TLHR64.., TLHY54../TLHY64.., TLHG54../TLHG64..

Parameter	Test Conditions	Type	Symbol	Value	Unit
Reverse voltage			$V_R$	6	V
DC forward current			$I_F$	30	mA
Surge forward current	$t_p \leq 10 \mu\text{s}$		$I_{FSM}$	1	A
Power dissipation	$T_{amb} \leq 50^{\circ}\text{C}$		$P_V$	100	mW
Junction temperature			$T_j$	100	$^{\circ}\text{C}$
Operating temperature range			$T_{amb}$	-20 to +100	$^{\circ}\text{C}$
Storage temperature range			$T_{stg}$	-55 to +100	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5 \text{ s}$ , 2 mm from body		$T_{sd}$	260	$^{\circ}\text{C}$
Thermal resistance junction/ambient			$R_{thJA}$	500	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

High efficiency red (TLHR54../TLHR64..)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$ , $I_{Vmin}/I_{Vmax} \geq 0.5$	TLHR5400/6400	$I_V$	1.6	3.5		mcd
		TLHR5401/6401	$I_V$	4	7		mcd
		TLHR5405/6405	$I_V$	6.3	10		mcd
		TLHR5413/6413	$I_V$	4		8	mcd
		TLHR5414/6414	$I_V$	6.3		12.5	mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	612		625	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		635		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 30$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2	3	V
Reverse voltage	$I_R = 10 \text{ mA}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1 \text{ MHz}$		$C_j$		50		pF

Yellow (TLHY54../TLHY64..)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$ , $I_{Vmin}/I_{Vmax} \geq 0.5$	TLHY5400/6400	$I_V$	1.6	3.5		mcd
		TLHY5401/6401	$I_V$	4	7		mcd
		TLHY5405/6405	$I_V$	6.3	10		mcd
		TLHY5413/6413	$I_V$	6.3		12.5	mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	581		594	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		585		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 30$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \text{ mA}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1 \text{ MHz}$		$C_j$		50		pF

**Green (TLHG54../TLHG64..)**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$ , $I_{V\text{min}}/I_{V\text{max}} \geq 0.5$	TLHG5400/6400	$I_V$	1.6	4		mcd
		TLHG5401/6401	$I_V$	4	7		mcd
		TLHG5405/6405	$I_V$	6.3	15		mcd
		TLHG5413/6413	$I_V$	6.3		12.5	mcd
		TLHG5414/6414	$I_V$	10		20	mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	562		575	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		565		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\varphi$		$\pm 30$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		50		pF

**Typical Characteristics ( $T_{\text{amb}} = 25^\circ\text{C}$ , unless otherwise specified)**

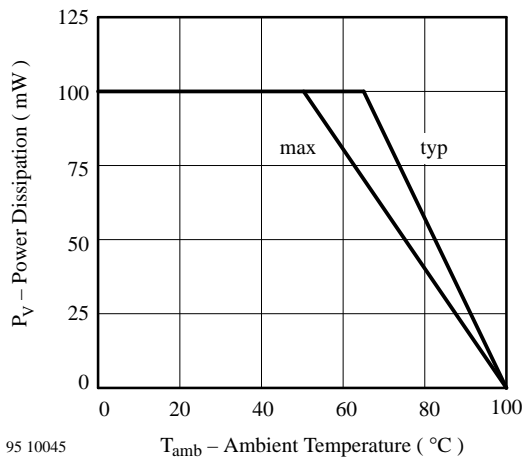


Figure 1. Power Dissipation vs. Ambient Temperature

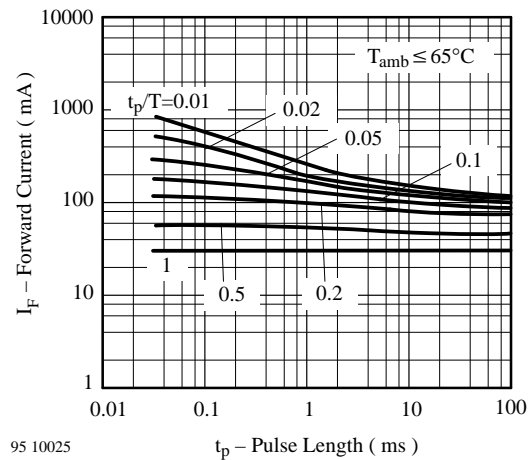


Figure 3. Forward Current vs. Pulse Length

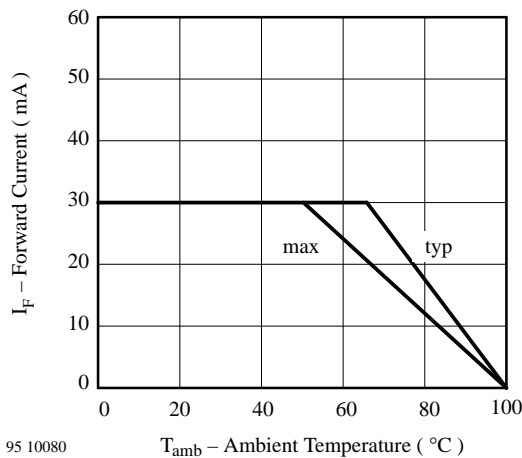


Figure 2. Forward Current vs. Ambient Temperature

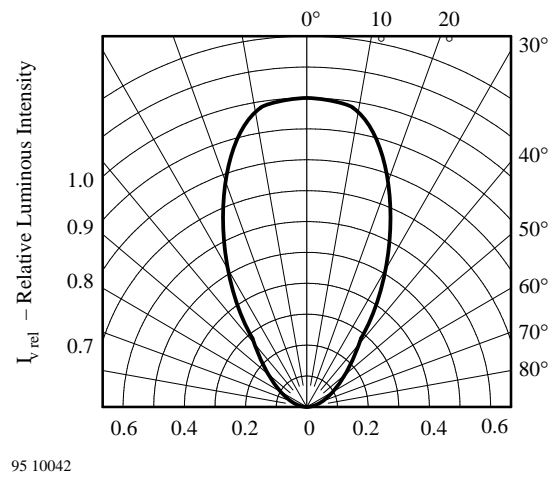


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

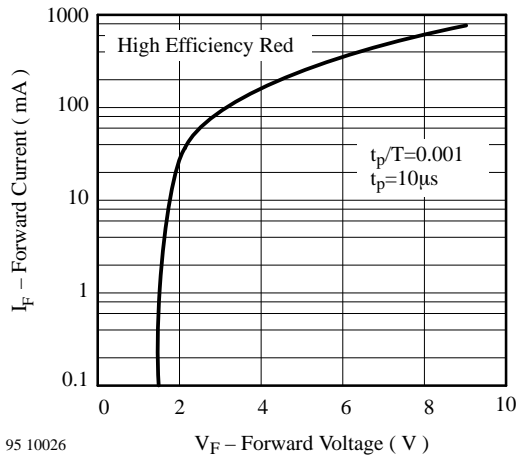


Figure 5. Forward Current vs. Forward Voltage

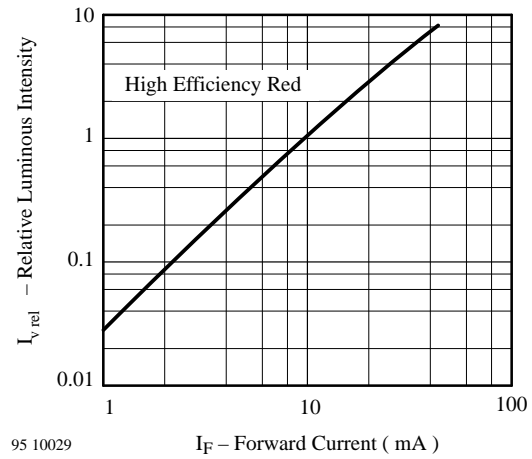


Figure 8. Relative Luminous Intensity vs. Forward Current

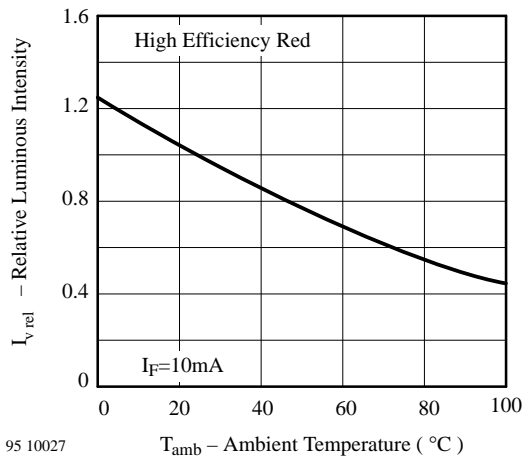


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

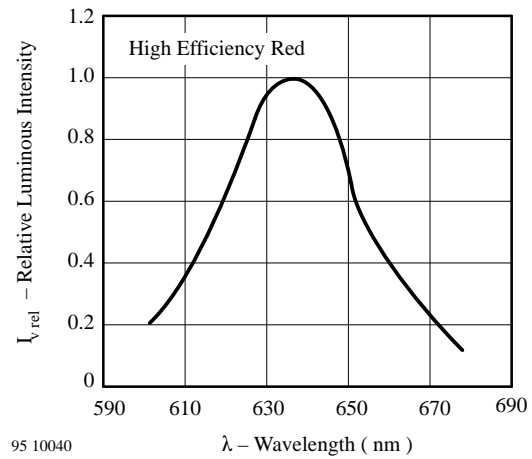


Figure 9. Relative Luminous Intensity vs. Wavelength

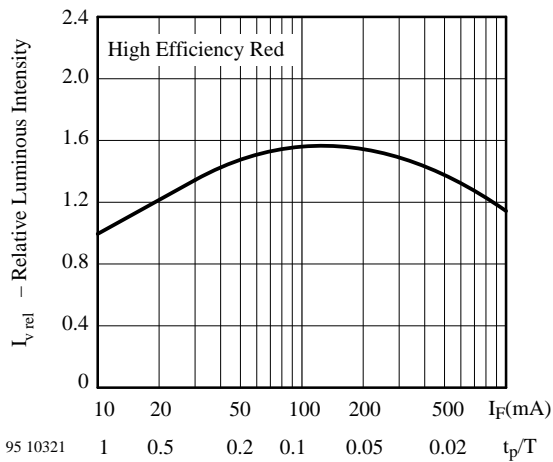


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

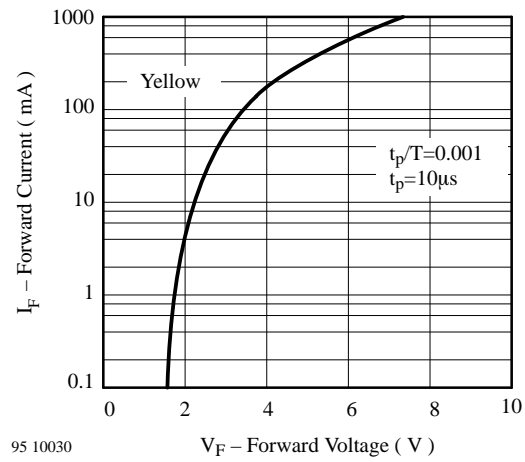


Figure 10. Forward Current vs. Forward Voltage

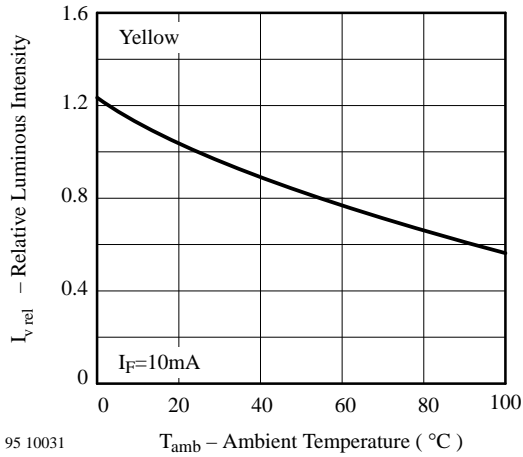


Figure 11. Rel. Luminous Intensity vs. Ambient Temperature

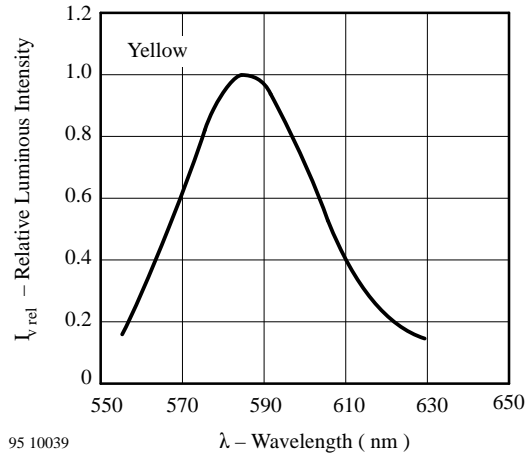


Figure 14. Relative Luminous Intensity vs. Wavelength

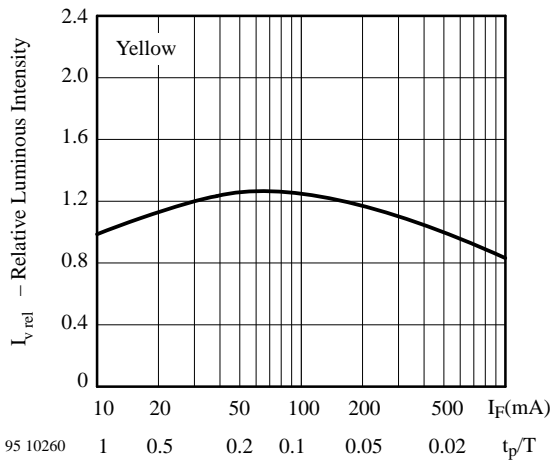


Figure 12. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

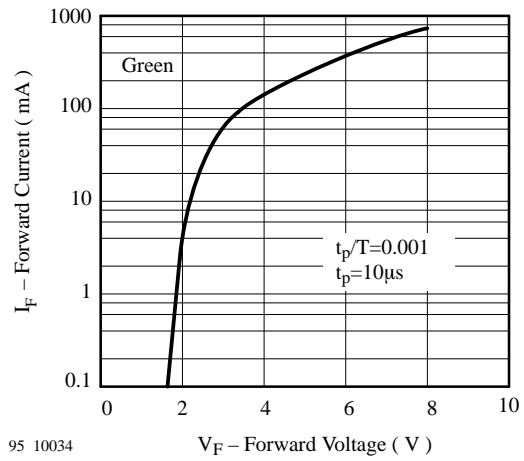


Figure 15. Forward Current vs. Forward Voltage

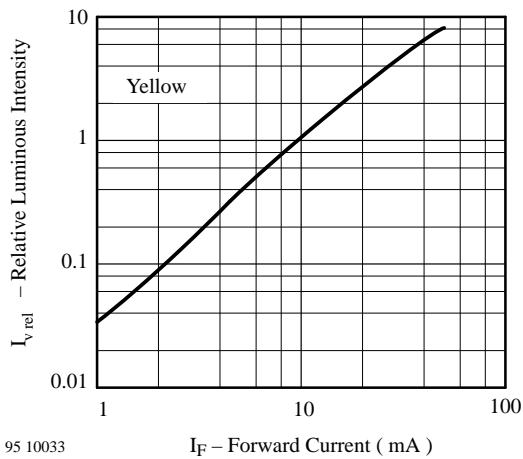


Figure 13. Relative Luminous Intensity vs. Forward Current

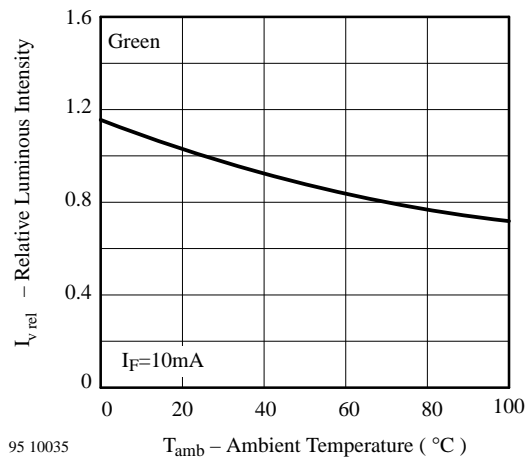


Figure 16. Rel. Luminous Intensity vs. Ambient Temperature

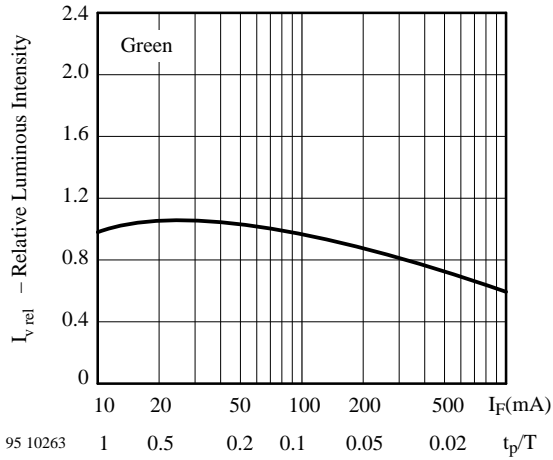


Figure 17. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

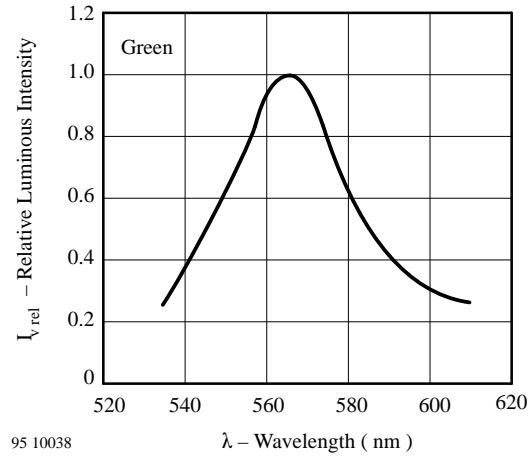


Figure 19. Relative Luminous Intensity vs. Wavelength

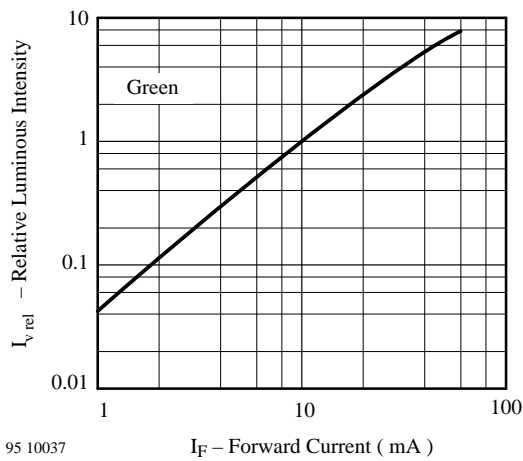
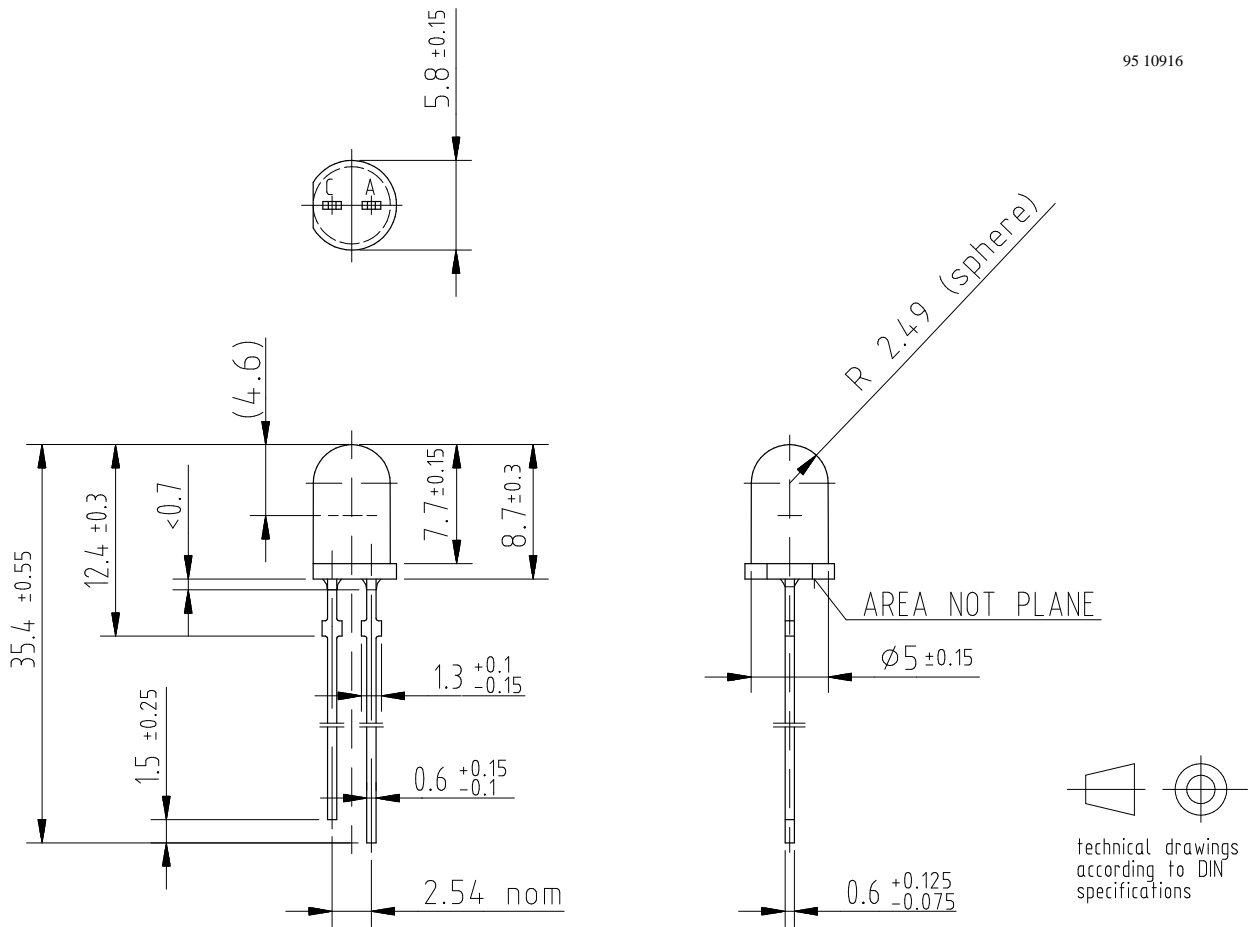


Figure 18. Relative Luminous Intensity vs. Forward Current

## Dimensions in mm

Package TLH.54..

95 10916



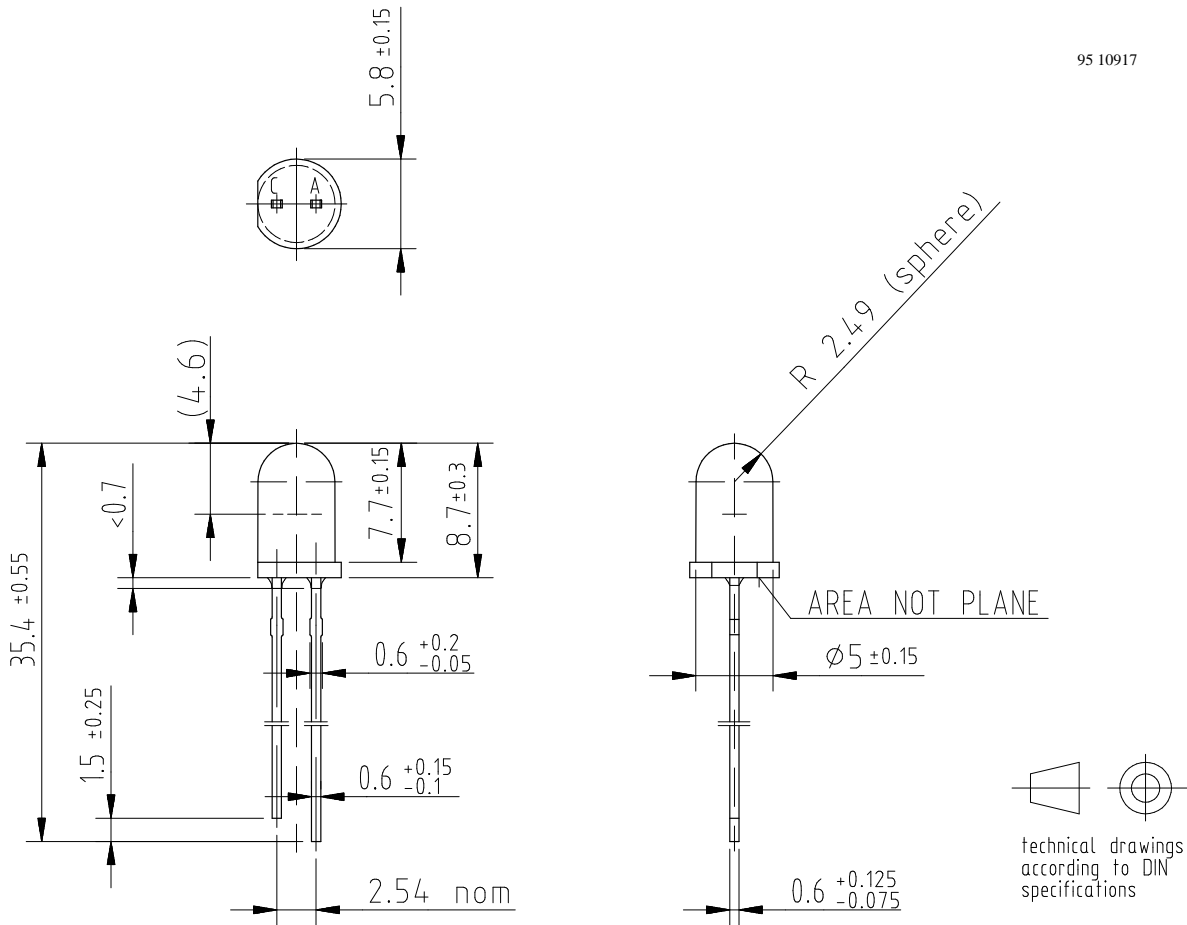
# TLH.54../64..

# TEMIC

TELEFUNKEN Semiconductors

Package TLH.64..

95 10917





## Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

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